UMZ1NT1G

Complementary Dual General Purpose Amplifier Transistor

PNP and NPN Surface Mount

Features

- High Voltage and High Current: $V_{CEO} = 50$ V, $I_C = 200$ mA
- High h_{FE} : $h_{FE} = 200 \sim 400$
- Moisture Sensitivity Level: 1
- ESD Rating Human Body Model: 3A – Machine Model: C
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	60	Vdc
Collector-Emitter Voltage	V _{(BR)CEO}	50	Vdc
Emitter-Base Voltage	V _{(BR)EBO}	7.0	Vdc
Collector Current – Continuous	Ι _C	200	mAdc

THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Мах	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	P _D	187 (Note 1) 256 (Note 2) 1.5 (Note 1) 2.0 (Note 2)	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	670 (Note 1) 490 (Note 2)	°C/W
Characteristic (Both Junctions Heated)	Symbol	Мах	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	P _D	250 (Note 1) 385 (Note 2) 2.0 (Note 1) 3.0 (Note 2)	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	493 (Note 1) 325 (Note 2)	°C/W
Thermal Resistance, Junction-to-Lead	$R_{\theta JL}$	188 (Note 1) 208 (Note 2)	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

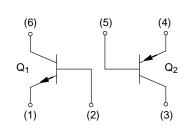
1. FR-4 @ Minimum Pad

2. FR-4 @ 1.0 x 1.0 inch Pad



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MARKING DIAGRAM



3Z = Device Code M = Date Code • = Pb-Free Package (Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
UMZ1NT1G	SC–88 (Pb–Free)	3000 / Tape & Reel
NSVUMZ1NT1G	SC-88 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Q1: NPN ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbo	l Min	Тур	Max	Unit
Collector–Emitter Breakdown Voltage $(I_{C} = 2.0 \text{ mAdc}, I_{B} = 0)$	V _{(BR)CE}	o 50	-	-	Vdc
Collector–Base Breakdown Voltage $(I_C = 10 \ \mu Adc, I_E = 0)$	V _{(BR)CB}	o 60	-	-	Vdc
Emitter–Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$	V _{(BR)EB}	0 7.0	-	-	Vdc
Collector-Base Cutoff Current ($V_{CB} = 45 \text{ Vdc}, I_E = 0$)	I _{CBO}	-	-	0.1	μAdc
	ICEO		_ _ _	0.1 2.0 1.0	μAdc μAdc mAdc
DC Current Gain (Note 3) (V _{CE} = 6.0 Vdc, I _C = 2.0 mAdc)	h _{FE}	200	-	400	-
Collector–Emitter Saturation Voltage ($I_c = 100 \text{ mAdc}, I_B = 10 \text{ mAdc}$)	V _{CE(sat}) –	-	0.25	Vdc
Transistor Frequency	f _T	-	114	-	MHz

3. Pulse Test: Pulse Width \leq 300 µs, D.C. \leq 2%.

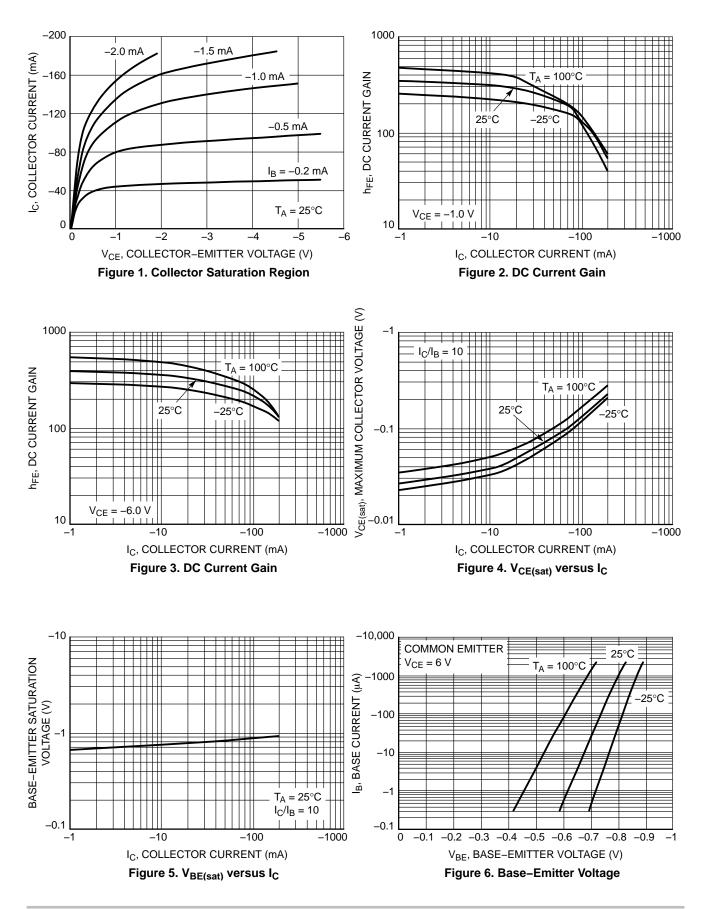
Q2: PNP

ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Collector–Emitter Breakdown Voltage $(I_{C} = 2.0 \text{ mAdc}, I_{B} = 0)$	V _{(BR)CEO}	-50	-	-	Vdc
Collector–Base Breakdown Voltage $(I_{C} = 10 \ \mu Adc, I_{E} = 0)$	V _{(BR)CBO}	-60	-	-	Vdc
Emitter–Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$	V _{(BR)EBO}	-7.0	-	-	Vdc
Collector–Base Cutoff Current ($V_{CB} = 45 \text{ Vdc}, I_E = 0$)	I _{CBO}	-	-	-0.1	μAdc
$\begin{array}{l} \mbox{Collector-Emitter Cutoff Current} \\ (V_{CE} = 10 \mbox{ Vdc}, I_B = 0) \\ (V_{CE} = 30 \mbox{ Vdc}, I_B = 0) \\ (V_{CE} = 30 \mbox{ Vdc}, I_B = 0, T_A = 80 \mbox{°C}) \end{array}$	I _{CEO}	_ _ _	_ _ _	-0.1 -2.0 -1.0	μAdc μAdc mAdc
DC Current Gain (Note 3) ($V_{CE} = 6.0$ Vdc, $I_C = 2.0$ mAdc)	h _{FE}	200	-	400	-
Collector–Emitter Saturation Voltage ($I_c = 100 \text{ mAdc}, I_B = 10 \text{ mAdc}$)	V _{CE(sat)}	-	-	-0.3	Vdc
Transistor Frequency	f _T	-	142	-	MHz

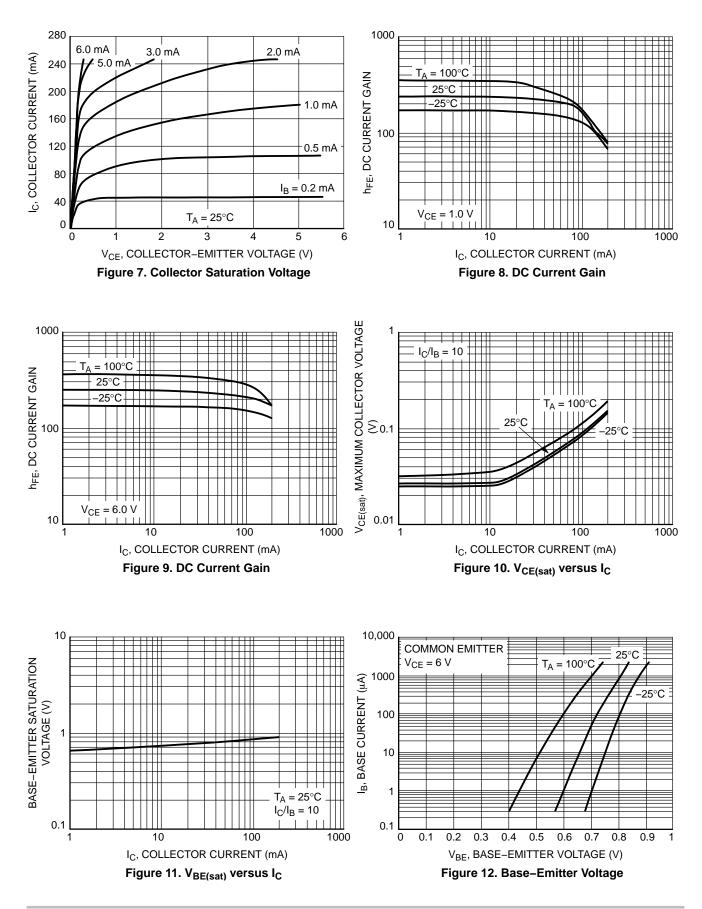
UMZ1NT1G

TYPICAL ELECTRICAL CHARACTERISTICS: PNP TRANSISTOR



UMZ1NT1G

TYPICAL ELECTRICAL CHARACTERISTICS: NPN TRANSISTOR



0.043

0.004





- XXX = Specific Device Code

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering

details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DATE 11 DEC 2012

STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2
STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2	STYLE 8: CANCELLED	STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2	STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2	STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2	STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2
STYLE 13:	STYLE 14:	STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:
PIN 1. ANODE	PIN 1. VREF	PIN 1. ANODE 1	PIN 1. BASE 1	PIN 1. BASE 1	PIN 1. VIN1
2. N/C	2. GND	2. ANODE 2	2. EMITTER 2	2. EMITTER 1	2. VCC
3. COLLECTOR	3. GND	3. ANODE 3	3. COLLECTOR 2	3. COLLECTOR 2	3. VOUT2
4. EMITTER	4. IOUT	4. CATHODE 3	4. BASE 2	4. BASE 2	4. VIN2
5. BASE	5. VEN	5. CATHODE 2	5. EMITTER 1	5. EMITTER 2	5. GND
6. CATHODE	6. VCC	6. CATHODE 1	6. COLLECTOR 1	6. COLLECTOR 1	6. VOUT1
STYLE 19:	STYLE 20:	STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:
PIN 1. I OUT	PIN 1. COLLECTOR	PIN 1. ANODE 1	PIN 1. D1 (i)	PIN 1. Vn	PIN 1. CATHODE
2. GND	2. COLLECTOR	2. N/C	2. GND	2. CH1	2. ANODE
3. GND	3. BASE	3. ANODE 2	3. D2 (i)	3. Vp	3. CATHODE
4. V CC	4. EMITTER	4. CATHODE 2	4. D2 (c)	4. N/C	4. CATHODE
5. V EN	5. COLLECTOR	5. N/C	5. VBUS	5. CH2	5. CATHODE
6. V REF	6. COLLECTOR	6. CATHODE 1	6. D1 (c)	6. N/C	6. CATHODE
STYLE 25:	STYLE 26:	STYLE 27:	STYLE 28:	STYLE 29:	STYLE 30:
PIN 1. BASE 1	PIN 1. SOURCE 1	PIN 1. BASE 2	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. SOURCE 1
2. CATHODE	2. GATE 1	2. BASE 1	2. DRAIN	2. ANODE	2. DRAIN 2
3. COLLECTOR 2	3. DRAIN 2	3. COLLECTOR 1	3. GATE	3. COLLECTOR	3. DRAIN 2
4. BASE 2	4. SOURCE 2	4. EMITTER 1	4. SOURCE	4. EMITTER	4. SOURCE 2
5. EMITTER	5. GATE 2	5. EMITTER 2	5. DRAIN	5. BASE/ANODE	5. GATE 1
6. COLLECTOR 1	6. DRAIN 1	6. COLLECTOR 2	6. DRAIN	6. CATHODE	6. DRAIN 1

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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